

#### **General Description**

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

#### **Features**

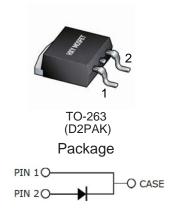
- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

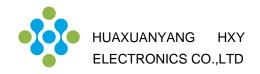
## **Applications**

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)
HSTPSC10H12GTR	TO-263(D2PAK)	800





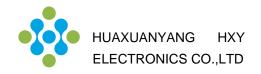


# **Maximum Ratings** (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	Vrrm	1200	V
Surge Peak Reverse Voltage	Vrsm	1200	V
DC Peak Reverse Voltage	VR	1200	V
Continuous Forward Current  Tc = 25°C  Tc = 135°C  Tc = 160°C	lF	30 15 10	А
Repetitive Peak Forward Surge Current  Tc = 25°C,tp=10ms,Half Sine Pulse  Tc = 110°C,tp=10ms,Half Sine Pulse	İFRM	57 41.5	А
Non-Repetitive Forward Surge Current  Tc = 25°C,tp=10ms,Half Sine Pulse  Tc = 110°C,tp=10ms,Half Sine Pulse	Ігѕм	90 69.5	А
$i^2$ dt value $T_C = 25^{\circ}C, t_p = 10 ms, Half Sine Pulse T_C = 110^{\circ}C, t_p = 10 ms, Half Sine Pulse$	∫ i²dt	40.5 24	A²s
Power dissipation $Tc = 25^{\circ}C$ $Tc = 110^{\circ}C$	Ptot	115 50	W
Operating junction Range	Tj	-55 to +175	°C
Storage temperature Range	T <sub>stg</sub>	-55 to +150	°C

## **Thermal Resistance**

Parameter	Symbol	Value	Unit
Thermal resistance, junction - case.	RthJC	1.30	°C/W



## Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.	5	rest Condition
Forward Voltage	VF				>	I <sub>F</sub> =10A
		-	1.4	1.7		T <sub>j</sub> =25°C
		-	2.0	-		Tj=175°C
Reverse Current					μΑ	V <sub>R</sub> =1200V
	lR	-	-	100		T <sub>j</sub> =25°C
		-	-	200		T <sub>j</sub> =175°C
Total Capacitive Charge	Qc		- 48 - nC			V <sub>R</sub> =800V,T <sub>j</sub> =25℃
		-		nC	$Q_C = \int_0^{V_R} C(V) dV$	
Total Capacitance	С				pF	Tj=25℃, f=1MHz
		-	695	-		V <sub>R</sub> =0V
		-	46	-		VR=400V
		-	35	-		Vr=800V

#### **Characteristics Curve:**

Fig 1: Forward Characteristics

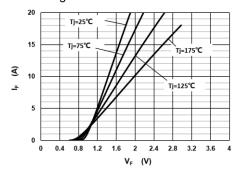


Fig 3: Current Derating

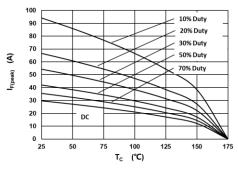


Fig 2: Reverse Characteristics

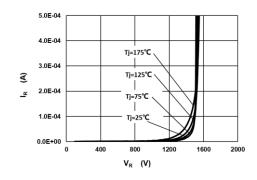
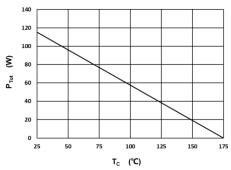


Fig 4: Power Derating





700

Fig 5: Capacitance vs. Reverse Voltage

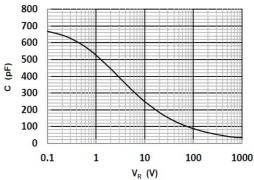


Fig 6: Reverse Charge vs. Reverse Voltage

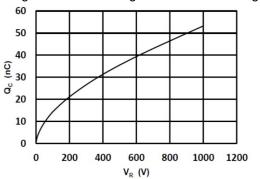


Fig 7: Typical Capacitance Stored Energy

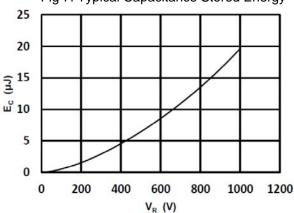
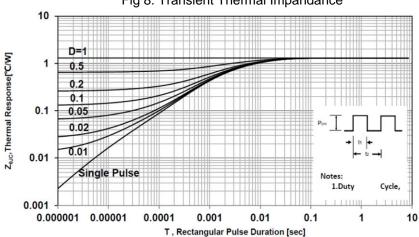
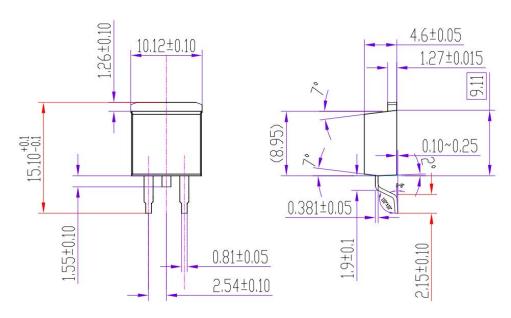


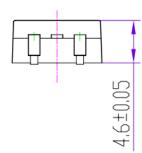
Fig 8: Transient Thermal Impandance



# **Package Dimensions**

Package TO-263(D2PAK)





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